

KSC2333

High Speed Switching Application • Low Collector Saturation Voltage

- Specified of Reverse Biased SOA With Inductive Load



NPN Epitaxial Silicon Transistor

1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	500	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current (DC)	2	А
I _{CP}	*Collector Current (Pulse)	4	А
I _B	Base Current (DC)	1	Α
P _C	Collector Dissipation (T _C =25°C)	15	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

^{*}PW≤350μs, Duty Cycle≤10%

Electrical Characteristics TC=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage	I _C = 0.5A, I _B =0.1A, L = 1mH	400		V
V _{CEX} (sus)1	Collector-Emitter Sustaining Voltage	$I_C = 0.5A$, $I_{B1} = -I_{B2} = 0.1A$ $T_C = 125^{\circ}C$, $L = 180\mu H$, clamped	450		V
V _{CEX} (sus)2	Collector-Emitter Sustaining Voltage	$I_C = 1A$, $I_{B1} = 0.2A$, $-I_{B2} = 0.2A$ $T_C = 125$ °C, $L = 180\mu H$, clamped	400		V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 400V, I_{E} = 0$		10	μΑ
I _{CER}	Collector Cut-off Current	$V_{CE} = 400V, R_{BE} = 51\Omega, T_{C} = 125^{\circ}C$		1	mA
I _{CEX1}	Collector Cut-off Current	$V_{CE} = 400V, V_{BE}(off) = -5V$		10	μΑ
I _{CEX2}	Collector Cut-off Current	$V_{CE} = 400V, V_{BE}(off) = -5V @ T_{C} = 125^{\circ}C$		1	mA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$		10	μΑ
h _{FE1} h _{FE2}	* DC Current Gain	$V_{CE} = 5V, I_{C} = 0.1A$ $V_{CE} = 5V, I_{C} = 0.5A$	20 10	80	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A		1	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A		1.2	V
t _{ON}	Turn ON Time	V _{CC} = 150V, I _C = 0.5A		1	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 0.1A$		2.5	μs
t _F	Fall Time	$R_L = 300\Omega$		1	μs

^{*} Pulse Test: PW≤350μs, Duty Cycle≤2%Pulsed

h_{FE} Classification

Classification	R	0	Y
h _{FE1}	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

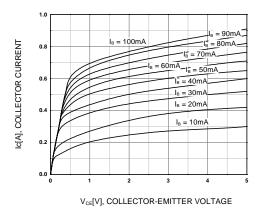


Figure 1. Static Characteristic

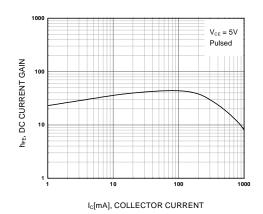


Figure 2. DC current Gain

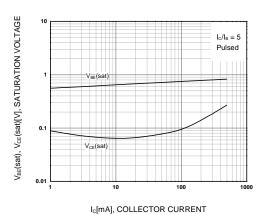


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

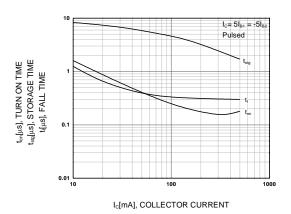


Figure 4. Turn On, Storage and Fall Time vs Collector Current

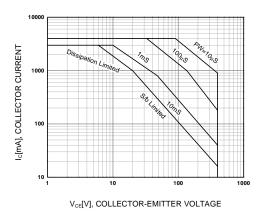


Figure 5. Forward Bias Safe Operating Area

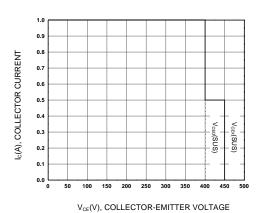
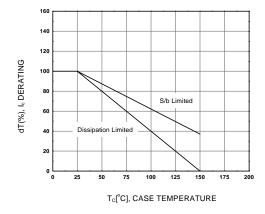
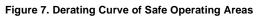


Figure 6. Reverse Bias Safe Operating Area

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Typical characteristics (Continued)





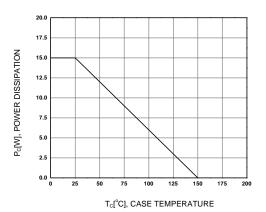
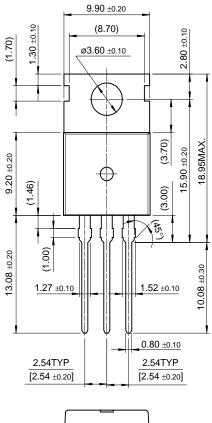
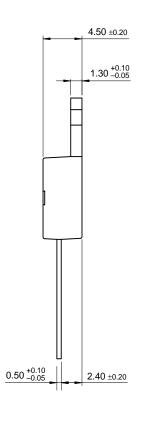


Figure 8. Power Derating

Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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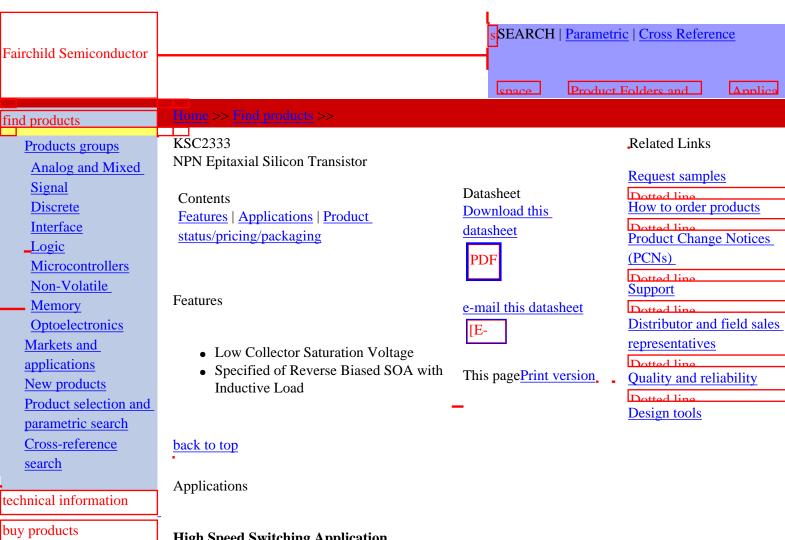
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSC2333Y	Full Production	\$0.347	TO-220	3	BULK
KSC2333YTU	Full Production	\$0.347	TO-220	3	RAIL

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